NSN 5962-01-356-8478

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View Online at https://aerobasegroup.com/nsn/5962-01-356-8
Operating Tempurature Range:
+0.0/+70.0 degrees celsius
Storage Tempurature Range:
-55.0/+125.0 degrees celsius
Features Provided:
High speed and low power and static operation and w/enable
Inclosure Material:
Ceramic or plastic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
25 input
Current Rating Per Characteristic:
80.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.3 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
10.00 input picofarads and 10.00 output picofarads
Time Rating Per Chacteristic:
150.00 nanoseconds access
Memory Device Type:
Ram
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:

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